

HIGH VOLTAGE FAST-SWITCHING NPN POWER TRANSISTOR

- SGS-THOMSON PREFERRED SALESTYPE
- HIGH VOLTAGE CAPABILITY
- U.L. RECOGNISED ISOWATT218 PACKAGE (U.L. FILE # E81734 (N)).

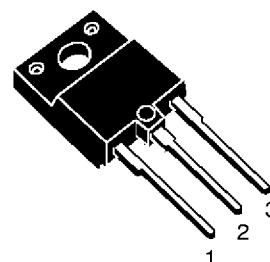
APPLICATIONS:

- HORIZONTAL DEFLECTION FOR COLOUR TV
- SWITCH MODE POWER SUPPLIES

DESCRIPTION

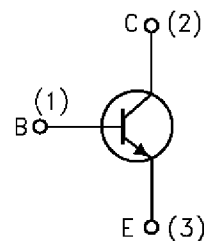
The BUH315 is manufactured using Multiepitaxial Mesa technology for cost-effective high performance and uses a Hollow Emitter structure to enhance switching speeds.

The BUH series is designed for use in horizontal deflection circuits in televisions and monitors.



ISOWATT218

INTERNAL SCHEMATIC DIAGRAM



SC08960

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage ($I_E = 0$)	1500	V

10	V	V_{EBO}	Emitter-Base Voltage ($I_C = 0$)	
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I_C	Collector Current	6	A
I_{CM}	Collector Peak Current ($t_p < 5$ ms)	12	A
I_B	Base Current	3	A
I_{BM}	Base Peak Current ($t_p < 5$ ms)	5	A
P_{tot}	Total Dissipation at $T_C = 25$ °C	44	W
T_{stg}	Storage Temperature	-65 to 150	°C
T_j	Max. Operating Junction Temperature	150	°C

THERMAL DATA

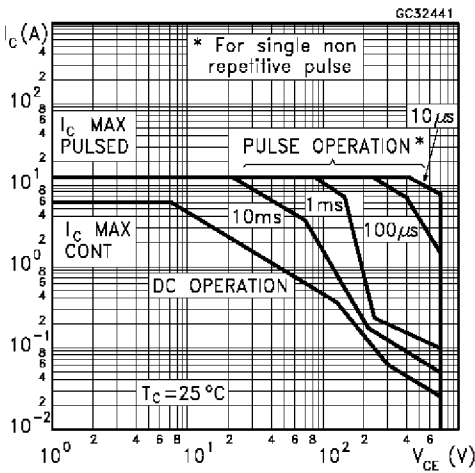
$R_{thj-case}$	Thermal Resistance Junction-case	Max	2.8	$^{\circ}C/W$
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ELECTRICAL CHARACTERISTICS ($T_{case} = 25^{\circ}C$ unless otherwise specified)

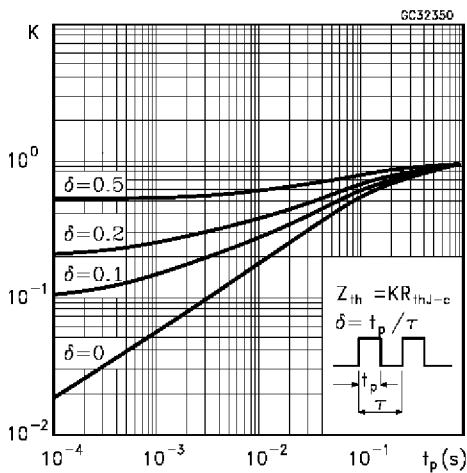
Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector Cut-off Current ($V_{BE} = 0$)	$V_{CE} = 1500 V$			200	μA
I_{EBO}	Emitter Cut-off Current ($I_C = 0$)	$V_{EB} = 5 V$			100	μA
$V_{CEO(sus)}$	Collector-Emitter Sustaining Voltage	$I_C = 100 mA$	700			V
V_{EBO}	Emitter-Base Voltage ($I_C = 0$)	$I_E = 10 mA$	10			V
$V_{CE(sat)*}$	Collector-Emitter Saturation Voltage	$I_C = 3 A \quad I_B = 0.75 A$			1.5	V
$V_{BE(sat)*}$	Base-Emitter Saturation Voltage	$I_C = 3 A \quad I_B = 0.75 A$			1.3	V
h_{FE*}	DC Current Gain	$I_C = 3 A \quad V_{CE} = 5 V$ $I_C = 3 A \quad V_{CE} = 5 V \quad T_j = 100^{\circ}C$	6 3.5		12	
t_s t_f	RESISTIVE LOAD Storage Time Fall Time	$V_{CC} = 400 V \quad I_C = 3 A$ $I_{B1} = 0.75 A \quad I_{B2} = 1.5 A$		1.6 110	2.4 200	μs ns
t_s t_f	INDUCTIVE LOAD Storage Time Fall Time	$I_C = 3 A \quad f = 15625 Hz$ $I_{B1} = 0.75 A \quad I_{B2} = -1.5 A$ $V_{ceflyback} = 1050 \sin\left(\frac{\pi}{5} 10^6\right) t \quad V$		3.5 340		μs ns
t_s t_f	INDUCTIVE LOAD Storage Time Fall Time	$I_C = 3 A \quad f = 31250 Hz$ $I_{B1} = 0.75 A \quad I_{B2} = -1.5 A$ $V_{ceflyback} = 1200 \sin\left(\frac{\pi}{5} 10^6\right) t \quad V$		3.5 270		μs ns

* Pulsed: Pulse duration = 300 μs , duty cycle 1.5 %

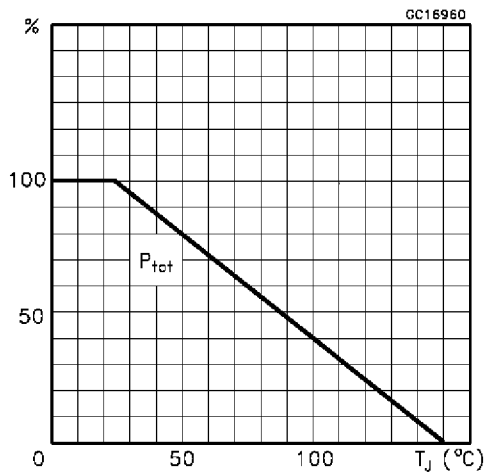
Safe Operating Area



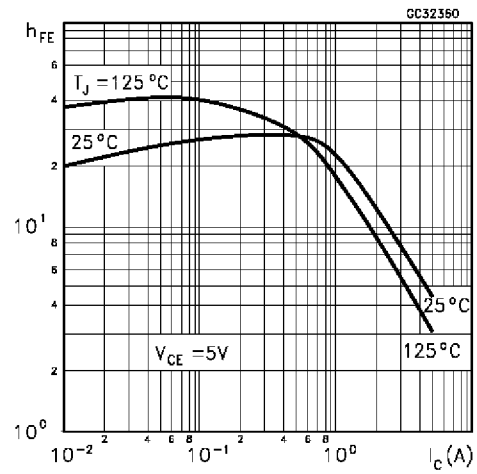
Thermal Impedance



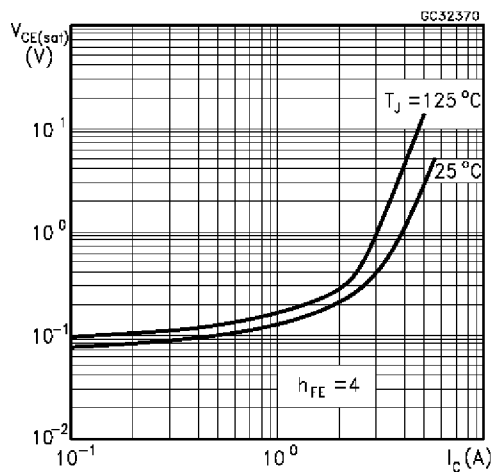
Derating Curve



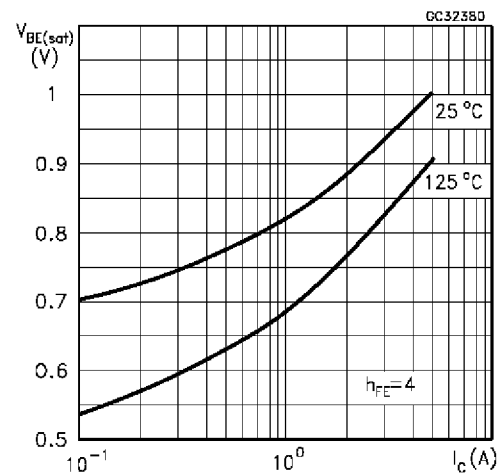
DC Current Gain



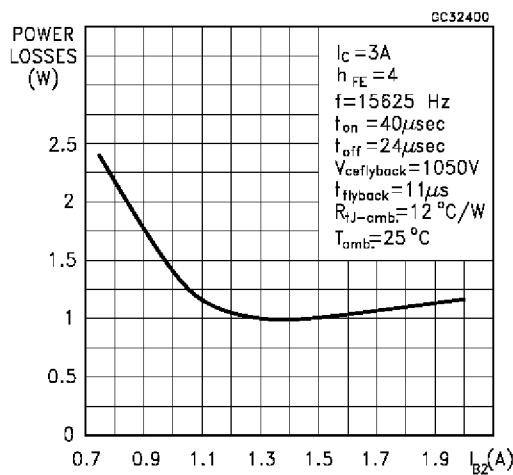
Collector Emitter Saturation Voltage



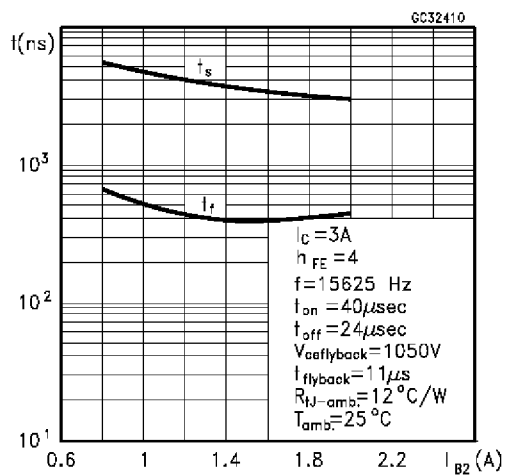
Base Emitter Saturation Voltage



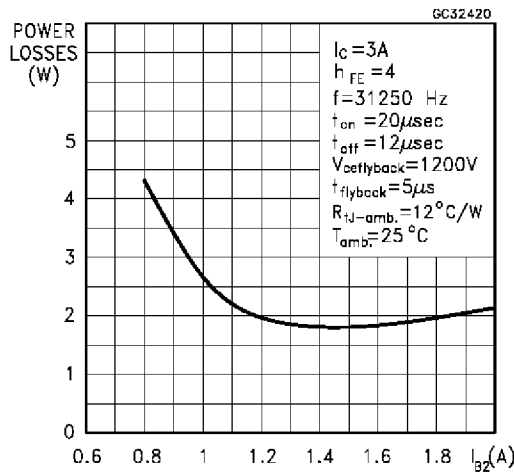
Power Losses at 16 KHz



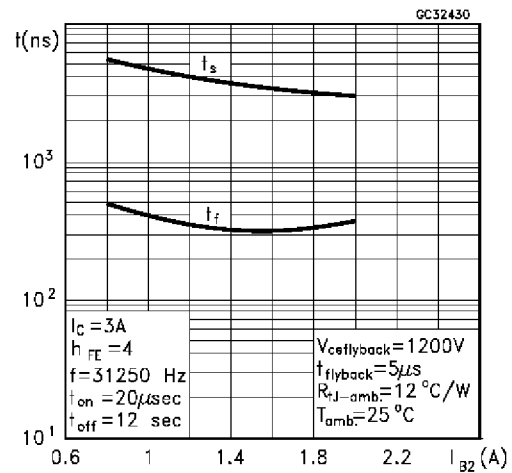
Switching Time Inductive Load at 16KHz
(see figure 2)



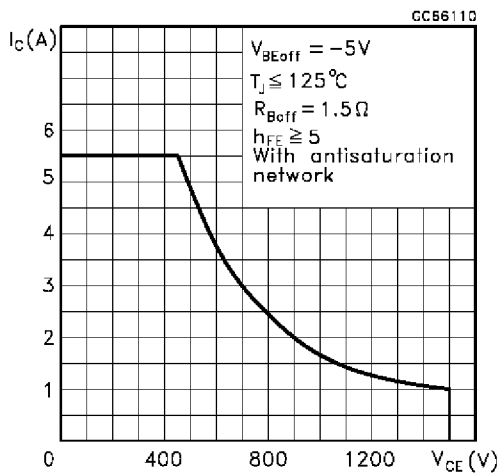
Power Losses at 32 KHz



Switching Time Inductive Load at 32 KHz
(see figure 2)



Reverse Biased SOA



BASE DRIVE INFORMATION

In order to saturate the power switch and reduce conduction losses, adequate direct base current I_{B1} has to be provided for the lowest gain h_{FE} at $100 \text{ }^\circ\text{C}$ (line scan phase). On the other hand, negative base current I_{B2} must be provided to turn off the power transistor (retrace phase).

Most of the dissipation, in the deflection application, occurs at switch-off. Therefore it is essential to determine the value of I_{B2} which minimizes power losses, fall time t_f and, consequently, T_j . A new set of curves have been defined to give total power losses, t_s and t_f as a function of I_{B2} at both 16 KHz and 32 KHz scanning frequencies for choosing the optimum negative drive. The test circuit is illustrated in

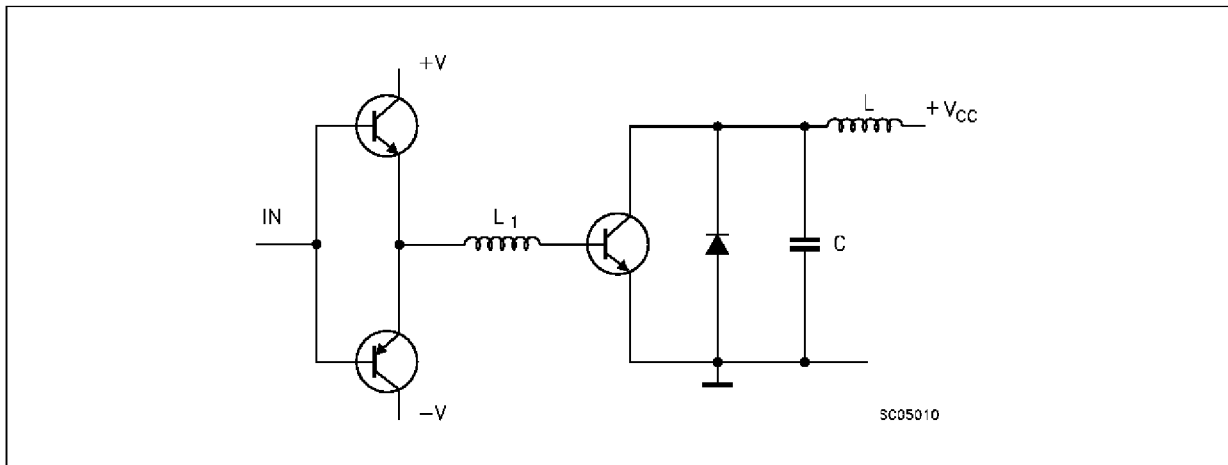
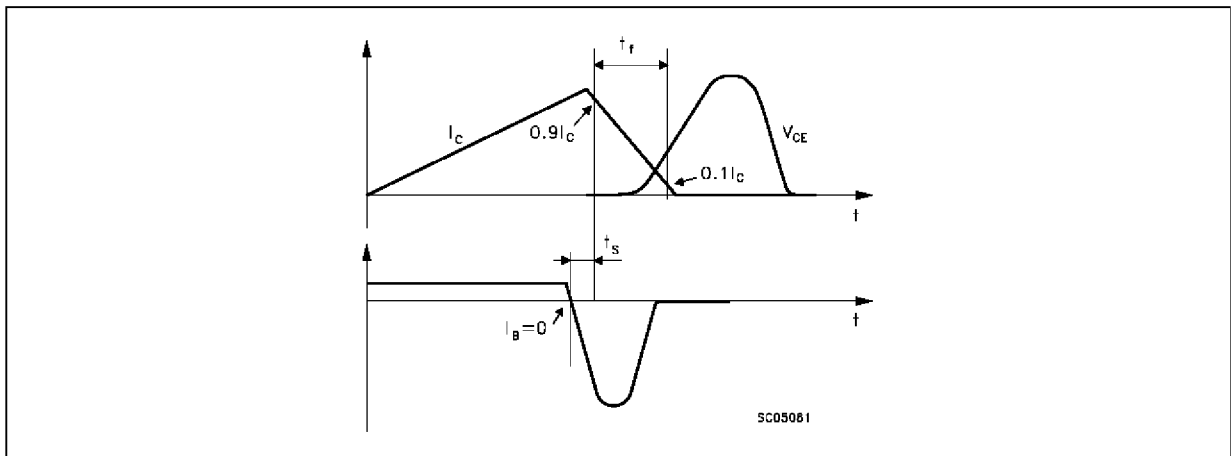
figure 1.

Inductance L_1 serves to control the slope of the negative base current I_{B2} to recombine the excess carrier in the collector when base current is still present, this would avoid any tailing phenomenon in the collector current.

The values of L and C are calculated from the following equations:

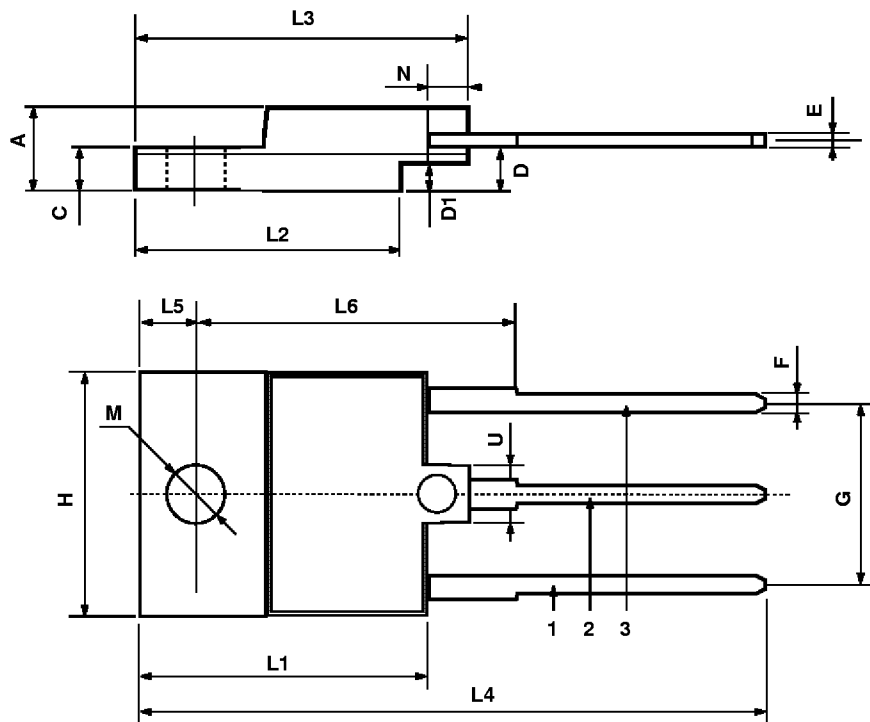
$$\frac{1}{2} L (I_C)^2 = \frac{1}{2} C (V_{CE(fly)})^2 \quad \omega = 2\pi f = \frac{1}{\sqrt{LC}}$$

Where I_C = operating collector current, $V_{CE(fly)}$ = flyback voltage, f = frequency of oscillation during retrace.

Figure 1: Inductive Load Switching Test Circuits.**Figure 2:** Switching Waveforms in a Deflection Circuit

ISOWATT218 MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A	5.35		5.65	0.210		0.222
C	3.3		3.8	0.130		0.149
D	2.9		3.1	0.114		0.122
D1	1.88		2.08	0.074		0.081
E	0.75		1	0.029		0.039
F	1.05		1.25	0.041		0.049
G	10.8		11.2	0.425		0.441
H	15.8		16.2	0.622		0.637
L1	20.8		21.2	0.818		0.834
L2	19.1		19.9	0.752		0.783
L3	22.8		23.6	0.897		0.929
L4	40.5		42.5	1.594		1.673
L5	4.85		5.25	0.190		0.206
L6	20.25		20.75	0.797		0.817
M	3.5		3.7	0.137		0.145
N	2.1		2.3	0.082		0.090
U		4.6			0.181	



P025C